

# Standard Rectifier Module

|                         |          |
|-------------------------|----------|
| <b>3~<br/>Rectifier</b> |          |
| $V_{RRM}$               | = 1600 V |
| $I_{DAV}$               | = 60 A   |
| $I_{FSM}$               | = 350 A  |

## 3~ Rectifier Bridge

Part number

**VUO52-16NO1**



Backside: isolated

 E72873



### Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

### Applications:

- Diode for main rectification
- For three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

### Package: V1-A-Pack

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Height: 17 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

### Disclaimer Notice

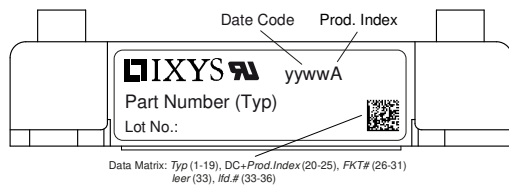
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| Rectifier  |  |                             |                   | Ratings                      |      |                                   |                  |
|------------|--|-----------------------------|-------------------|------------------------------|------|-----------------------------------|------------------|
| Symbol     | Definition                                   | Conditions                  |                   | min.                         | typ. | max.                              | Unit             |
| $V_{RSM}$  | max. non-repetitive reverse blocking voltage |                             |                   |                              |      | 1700                              | V                |
| $V_{RRM}$  | max. repetitive reverse blocking voltage     |                             |                   |                              |      | 1600                              | V                |
| $I_R$      | reverse current                              | $V_R = 1600$ V              |                   | $T_{VJ} = 25^\circ\text{C}$  |      | 40                                | $\mu\text{A}$    |
|            |  | $V_R = 1600$ V              |                   | $T_{VJ} = 150^\circ\text{C}$ |      | 1.5                               | mA               |
| $V_F$      | forward voltage drop                         | $I_F = 20$ A                |                   | $T_{VJ} = 25^\circ\text{C}$  |      | 1.13                              | V                |
|            |  | $I_F = 60$ A                |                   |                              |      | 1.44                              | V                |
|            |  | $I_F = 20$ A                |                   | $T_{VJ} = 125^\circ\text{C}$ |      | 1.07                              | V                |
|            |  | $I_F = 60$ A                |                   |                              |      | 1.50                              | V                |
| $I_{DAV}$  | bridge output current                        | $T_C = 110^\circ\text{C}$   |                   | $T_{VJ} = 150^\circ\text{C}$ |      | 60                                | A                |
|            |  | rectangular                 | $d = \frac{1}{3}$ |                              |      |                                   |                  |
| $V_{FO}$   | threshold voltage                            |                             |                   | $T_{VJ} = 150^\circ\text{C}$ |      | 0.83                              | V                |
| $r_F$      | slope resistance                             |                             |                   |                              |      | 11.5                              | m $\Omega$       |
|            |  |                             |                   |                              |      | } for power loss calculation only |                  |
| $R_{thJC}$ | thermal resistance junction to case          |                             |                   |                              |      | 1.3                               | K/W              |
| $R_{thCH}$ | thermal resistance case to heatsink          |                             |                   |                              | 0.3  |                                   | K/W              |
| $P_{tot}$  | total power dissipation                      |                             |                   | $T_C = 25^\circ\text{C}$     |      | 95                                | W                |
| $I_{FSM}$  | max. forward surge current                   | $t = 10$ ms; (50 Hz), sine  |                   | $T_{VJ} = 45^\circ\text{C}$  |      | 350                               | A                |
|            |  | $t = 8,3$ ms; (60 Hz), sine |                   | $V_R = 0$ V                  |      | 380                               | A                |
|            |  | $t = 10$ ms; (50 Hz), sine  |                   | $T_{VJ} = 150^\circ\text{C}$ |      | 300                               | A                |
|            |  | $t = 8,3$ ms; (60 Hz), sine |                   | $V_R = 0$ V                  |      | 320                               | A                |
| $I^2t$     | value for fusing                             | $t = 10$ ms; (50 Hz), sine  |                   | $T_{VJ} = 45^\circ\text{C}$  |      | 615                               | A <sup>2</sup> s |
|            |  | $t = 8,3$ ms; (60 Hz), sine |                   | $V_R = 0$ V                  |      | 600                               | A <sup>2</sup> s |
|            |  | $t = 10$ ms; (50 Hz), sine  |                   | $T_{VJ} = 150^\circ\text{C}$ |      | 450                               | A <sup>2</sup> s |
|            |  | $t = 8,3$ ms; (60 Hz), sine |                   | $V_R = 0$ V                  |      | 425                               | A <sup>2</sup> s |
| $C_J$      | junction capacitance                         | $V_R = 400$ V; $f = 1$ MHz  |                   | $T_{VJ} = 25^\circ\text{C}$  |      | 10                                | pF               |



| Package V1-A-Pack |  | Ratings   |      |      |      |      |
|-------------------|--|---|------|------|------|------|
| Symbol            | Definition   | Conditions  | min. | typ. | max. | Unit |
| $I_{RMS}$         | RMS current  | per terminal  |      |      | 100  | A    |
| $T_{VJ}$          | virtual junction temperature                                 |   | -40  |      | 150  | °C   |
| $T_{op}$          | operation temperature  |   | -40  |      | 125  | °C   |
| $T_{stg}$         | storage temperature  |   | -40  |      | 125  | °C   |
| <b>Weight</b>     |  |   |      | 37   |      | g    |
| $M_D$             | mounting torque  |   | 2    |      | 2.5  | Nm   |
| $d_{Spp/App}$     | creepage distance on surface   striking distance through air | terminal to terminal                                | 6.0  |      |      | mm   |
| $d_{Spb/Apb}$     |  | terminal to backside                                | 12.0 |      |      | mm   |
| $V_{ISOL}$        | isolation voltage  | t = 1 second<br>50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA | 3600 |      |      | V    |
|                   |  | t = 1 minute  | 3000 |      |      | V    |



| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | VUO52-16NO1     | VUO52-16NO1        | Blister       | 24       | 515842   |

| Similar Part | Package   | Voltage class |
|--------------|-----------|---------------|
| VUO52-08NO1  | V1-A-Pack | 800           |
| VUO52-12NO1  | V1-A-Pack | 1200          |
| VUO52-14NO1  | V1-A-Pack | 1400          |
| VUO52-18NO1  | V1-A-Pack | 1800          |

|             |           |      |
|-------------|-----------|------|
| VUO52-20NO1 | V1-A-Pack | 2000 |
| VUO52-22NO1 | V1-A-Pack | 2200 |
| VUO34-16NO1 | V1-A-Pack | 1600 |
| VUO34-18NO1 | V1-A-Pack | 1800 |

**Equivalent Circuits for Simulation**

\* on die level

$T_{VJ} = 150^{\circ}C$



Rectifier

|              |                    |      |    |
|--------------|--------------------|------|----|
| $V_{0\ max}$ | threshold voltage  | 0.83 | V  |
| $R_{0\ max}$ | slope resistance * | 10.2 | mΩ |



**Outlines V1-A-Pack**



**Remarks / Bemerkungen:**

1. Nominal distance mounting screws on heat sink: 52 mm / Nennabstand Befestigungsschrauben auf Kühlkörper: 52 mm
2. General tolerance / Allgemeintoleranz: DIN ISO 2768 -T1-c
3. Surface treatment of pins: tin plated (Sn) in hot dip / Oberflächenbehandlung der Pins: verzinkt (Sn) im Tauchbad
4. Detail X: EJOT PT® self-tapping screws (dimension K25) to be recommended for mounting on PCB  
selbstschneidende Schraube (Größe K25) empfohlen für die PCB-Montage  
Take care on the maximum screw length according to board thickness and the maximum hole depth of 6 mm<sup>L</sup>  
Bei der Wahl der Schraubenlänge die PCB-Dicke und die maximale Lochtiefe von 6mm beachten  
Recommended mounting torque: 1.5 Nm / Empfohlenes Drehmoment: 1.5 Nm





**Rectifier**



Fig. 1 Forward current vs. voltage drop per diode



Fig. 2 Surge overload current vs. time per diode

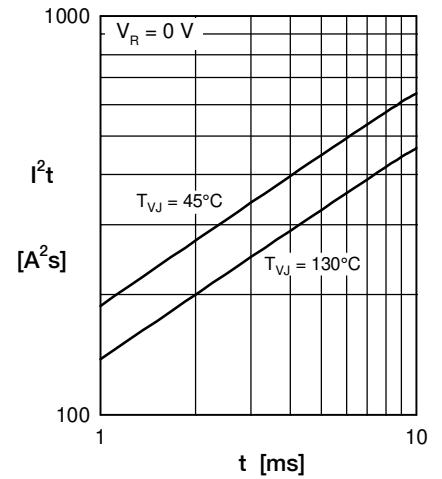


Fig. 3  $I^2t$  vs. time per diode



Fig. 4 Power dissipation vs. forward current and ambient temperature per diode



Fig. 5 Max. forward current vs. case temperature per diode



Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for  $Z_{thJC}$  calculation:

| i | $R_{th}$ (K/W) | $t_i$ (s) |
|---|----------------|-----------|
| 1 | 0.06070        | 0.008     |
| 2 | 0.173          | 0.05      |
| 3 | 0.3005         | 0.06      |
| 4 | 0.463          | 0.3       |
| 5 | 0.3028         | 0.15      |

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Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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